

CMOS 8-Bit Microcontroller

TMP87CH70BF, TMP87CM70BF

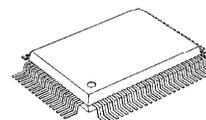
The 87CH70B/M70B are the high speed and high performance 8-bit single chip microcomputers. These MCU contain 6-bit A/D conversion inputs and a VFT (Vacuum Fluorescent Tube) driver on a chip.

Part No.	ROM	RAM	Package	OTP MCU
TMP87CH70BF	16 K × 8-bit	512 × 8-bit	P-QFP80-1420-0.80B	TMP87PM70F
TMP87CM70BF	32 K × 8-bit			

Features

- ◆ 8-bit single chip microcomputer TLCS-870 Series
- ◆ Instruction execution time: 0.5 μ s (at 8 MHz), 122 μ s (at 32.768 kHz)
- ◆ 412 basic instructions
 - Multiplication and Division (8 bits × 8 bits, 16 bits ÷ 8 bits)
 - Bit manipulations (Set/Clear/Complement/Move/Test/Exclusive or)
 - 16-bit data operations
 - 1-byte jump/subroutine-call (Short relative jump/ Vector call)
- ◆ 14 interrupt sources (External: 5, Internal: 9)
 - All sources have independent latches each, and nested interrupt control is available.
 - 3 edge-selectable external interrupts with noise reject
 - High-speed task switching by register bank changeover
- ◆ 10 Input/Output ports (73 pins)
 - Output: 1 port (8 pins)
 - Input/Output: 9 ports (65 pins)
- ◆ Two 16-bit Timer/Counters
 - Timer, Event counter modes
- ◆ Two 8-bit Timer/Counters
 - Timer, Event counter, Capture (Pulse width/duty measurement), PWM output, Programmable divider output modes
- ◆ Time Base Timer (Interrupt frequency: 1 Hz to 16 kHz)
- ◆ Divider output function (frequency: 1 kHz to 8 kHz)
- ◆ Watchdog Timer
 - Interrupt source/reset output (programmable)
- ◆ 8-bit Serial Interface
 - With 8 bytes transmit/receive data buffer
 - Internal/external serial clock, and 4/8-bit mode
- ◆ 8-bit High Speed Serial Output (rate: max. 1 bit/ μ s)
- ◆ 6-bit A/D conversion input (6 channels)

P-QFP80-1420-0.08B



TMP87CH70BF
 TMP87CM70BF
 TMP87PM70F

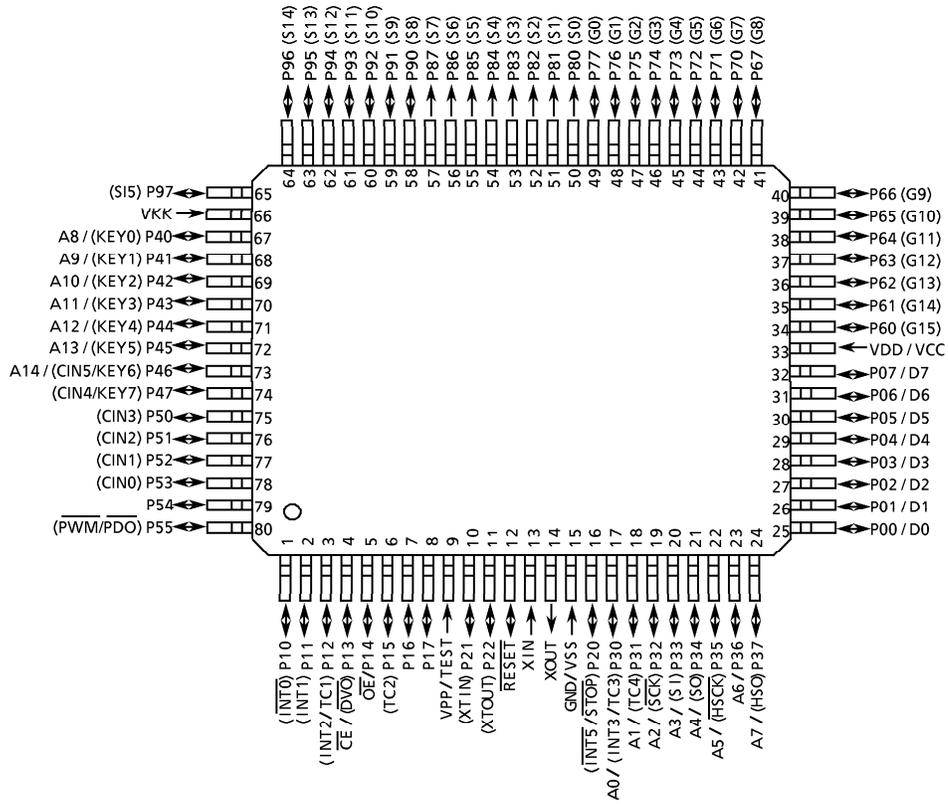
000707EBP1

- For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance / Handling Precautions.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

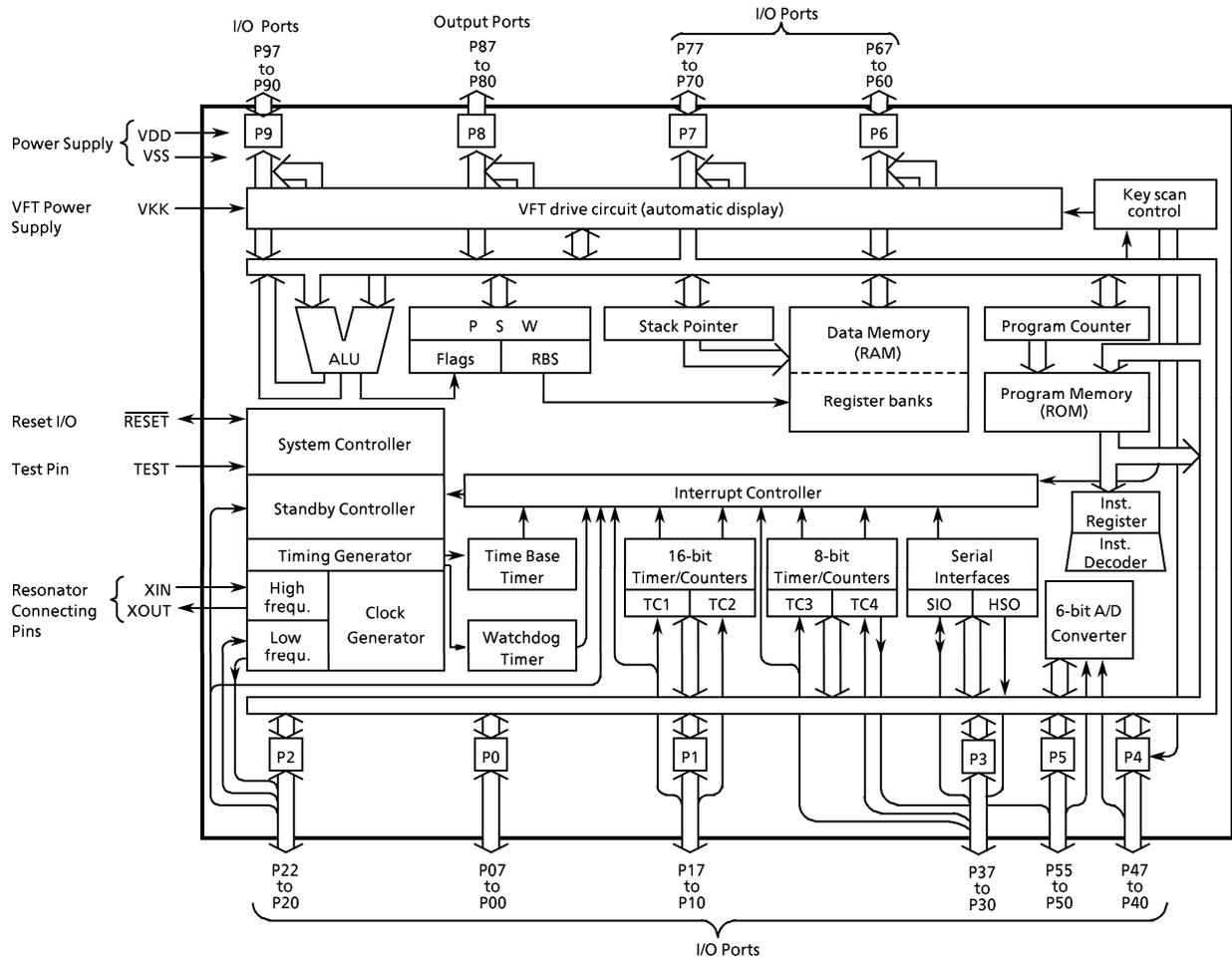
- ◆ Vacuum Fluorescent Tube Driver (automatic display)
 - High breakdown voltage ports (max. 40 V × 32 bits)
- ◆ Key scanning function
 - Key-matrix constructed by segment outputs (1 to 16) and key inputs (1 to 8)
- ◆ Dual clock operation
 - Single/Dual-clock mode (option)
- ◆ Five Power saving operating modes
 - STOP mode: Oscillation stops. Battery/Capacitor back-up. Port output hold/High-impedance.
 - SLOW mode: Low power consumption operation using low-frequency clock (32.768 kHz).
 - IDLE1 mode: CPU stops, and Peripherals operate using high-frequency clock. Release by interrupts.
 - IDLE2 mode: CPU stops, and Peripherals operate using high-and low-frequency clock. Release by interrupts.
 - SLEEP mode: CPU stops, and Peripherals operate using low-frequency clock. Release by interrupts.
- ◆ Wide operating voltage: 2.7 to 5.5 V at 4.19 MHz / 32.768 kHz,
4.5 to 5.5 V at 8 MHz / 32.768 kHz (87CH70B/M70B)
4.5 to 6 V at 8 MHz / 32.768 kHz (87PM70)
- ◆ Emulation Pod: BM87CK70F0B (or BM87CK70F0A)

Pin Assignments (Top View)

P-QFP80-1420-0.80B



Block Diagram



Pin Function

Pin Name	Input / Output	Function		
P07 to P00	I/O	Two 8-bit programmable input/output ports (tri-state).		
P17, P16, P14	I/O			
P15 (TC2)	I/O (Input)	Each bit of these ports can be individually configured as an input or an output under software control. During reset, all bits are configured as inputs. When used as a divider output, the latch must be set to "1".	Timer/Counter 2 input	
P13 (\overline{DVO})	I/O (Output)		Divider output	
P12 (INT2 / TC1)	I/O (Input)		External interrupt input 2 or Timer/Counter 1 input	
P11 (INT1)			External interrupt input 1	
P10 ($\overline{INT0}$)			External interrupt input 0	
P22 (XTOUT)	I/O (Output)	3-bit input/output port with latch. When used as an input port, the latch must be set to "1".	Resonator connecting pins (32.768 kHz). For inputting external clock, XTIN is used and XTOUT is opened.	
P21 (XTIN)	I/O (Input)			External interrupt input 5 or STOP mode release signal input
P20 ($\overline{INT5/STOP}$)				
P37 (HSO)	I/O (Output)	8-bit input/output port with latch. When used as an input port, a HSO output, a SIO input/output, a timer/counter input, or an interrupt input, the latch must be set to "1".	HSO serial data output	
P36	I/O			
P35 (\overline{HSCK})	I/O (Output)		HSO serial clock output	
P34 (SIO)			SIO serial data output	
P33 (SIO)	I/O (Input)		SIO serial data input	
P32 (\overline{SCK})	I/O (I/O)		SIO serial clock input/output	
P31 (TC4)	I/O (Input)		Timer/Counter 4 input	
P30 (INT3 / TC3)			External interrupt input 3 or Timer/Counter 3 input	
P47 (CIN4 / KEY7), P46 (CIN5 / KEY6) P45 (KEY5) to P40 (KEY0)			I/O (Input)	Comparator inputs or Key scan inputs Key scan inputs
P55 ($\overline{PWM/PDO}$)	I/O (Output)		6-bit input/output port with latch. When used as an input port, a comparator input, or a PWM/PDO output, the latch must be set to "1".	8-bit PWM output or 8-bit programmable divider output
P54	I/O			
P53 (CIN0) to P50 (CIN3)	I/O (Input)	Comparator inputs		
P67 (G8) to P60 (G15)	I/O (Output)	Three 8-bit high breakdown voltage I/O ports with the latch. When used as a VFT driver output, the latch must be cleared to "0".	VFT digit driver outputs	
P77 (G0) to P70 (G7)				
P97 (S15) to P90 (S8)			VFT segment driver outputs (Key strobe outputs)	
P87 (S7) to P80 (S0)	Output (Output)	8-bit high breakdown voltage output port with latch. When used as VFT driver output, the latch must be cleared to "0".		
XIN, XOUT	Input, Output	Resonator connecting pins for high-frequency clock. For inputting external clock, XIN is used and XOUT is opened.		
RESET	I/O	Reset signal input or watchdog timer output/address-trap-reset output/system-clock-reset output.		
TEST	Input	Test pin for out-going test. Be tied to low.		
VDD, VSS	Power Supply	+ 5 V, 0 V (GND)		
VKK		VFT driver power supply		

OPERATIONAL DESCRIPTION

1. CPU CORE FUNCTIONS

The CPU core consists of a CPU, a system clock controller, an interrupt controller, and a watchdog timer. This section provides a description of the CPU core, the program memory (ROM), the data memory (RAM), and the reset circuit.

1.1 Memory Address Map

The TLCS-870 Series is capable of addressing 64K bytes of memory. Figure 1-1 shows the memory address maps of the 87CH70B/M70B. In the TLCS-870 Series, the memory is organized 4 address spaces (ROM, RAM, SFR, and DBR). It uses a memory mapped I/O system, and all I/O registers are mapped in the SFR/DBR address spaces. There are 16 banks of general-purpose registers. The register banks are also assigned to the first 128 bytes of the RAM address space.

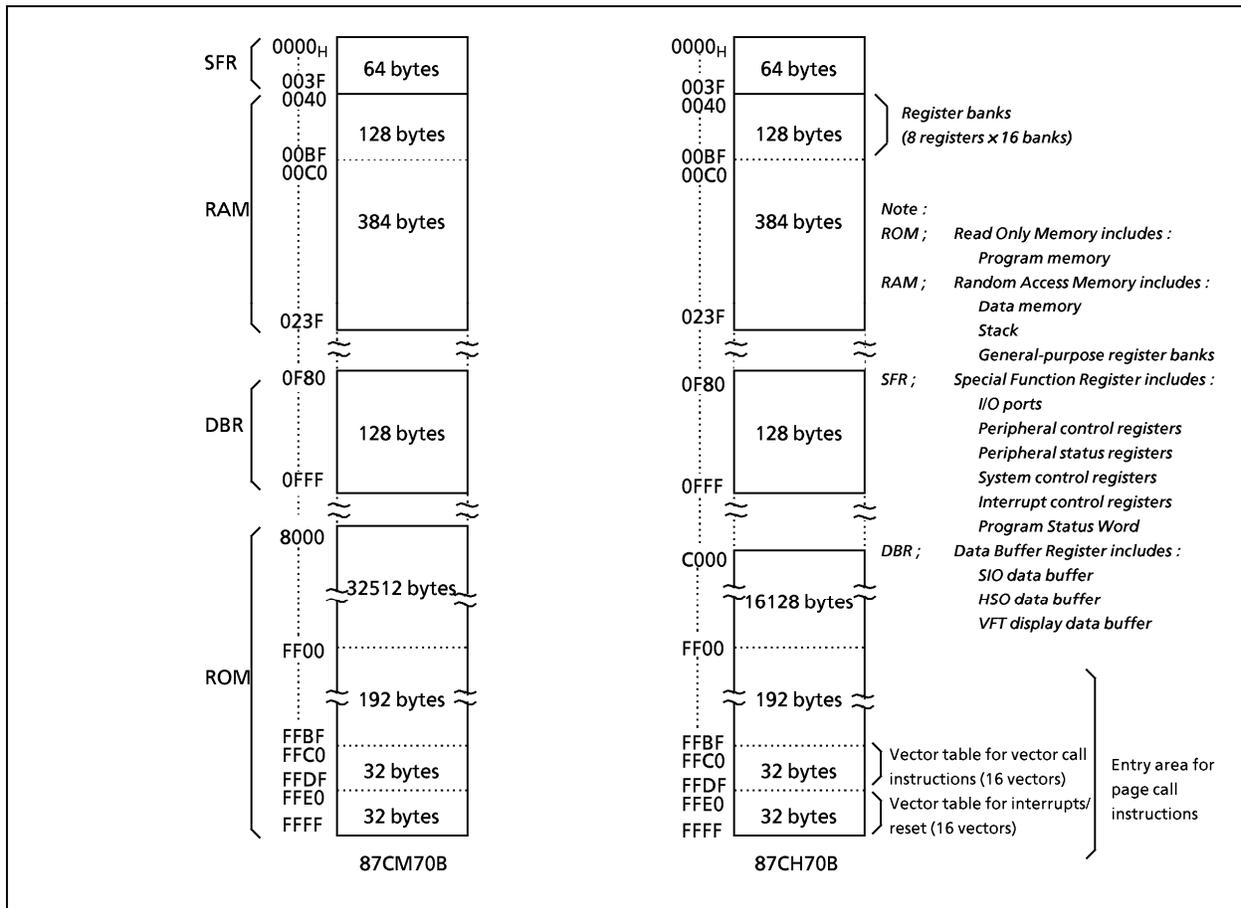


Figure 1-1. Memory Address Maps

Electrical Characteristics

Absolute Maximum Ratings

(V_{SS} = 0 V)

Parameter	Symbol	Conditions	Ratings	Unit
Supply Voltage	V _{DD}		- 0.3 to 6.5	V
Input Voltage	V _{IN}		- 0.3 to V _{DD} + 0.3	V
Output Voltage	V _{OUT1}	P2, P3, P4, P5, XOUT, RESET	- 0.3 to V _{DD} + 0.3	V
	V _{OUT3}	Source open drain ports	V _{DD} - 40 to V _{DD} + 0.3	
Output Current (Per 1 pin)	I _{OUT1}	P0, P1, P2, P3, P4, P5	3.2	mA
	I _{OUT3}	P8, P9 (segment outputs)	- 12	
	I _{OUT4}	P6, P7 (digit outputs)	- 25	
Output Current (Total)	Σ I _{OUT1}	P0, P1, P2, P3, P4, P5	120	mA
	Σ I _{OUT2}	P6, P7, P8, P9	- 120	
Power Dissipation [T _{opr} = 70°C]	PD		350	mW
Soldering Temperature (time)	T _{sld}		260 (10 s)	°C
Storage Temperature	T _{stg}		- 55 to 125	°C
Operating Temperature	T _{opr}		- 30 to 70	°C

Note: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Recommended Operating Conditions

(V_{SS} = 0 V, T_{opr} = - 30 to 70 °C)

Parameter	Symbol	Pins	Conditions	Min	Max	Unit	
Supply Voltage	V _{DD}		f _c = 8 MHz	NORMAL1, 2 modes	4.5	5.5	V
				IDLE1, 2 modes			
			f _c = 4.2 MHz	NORMAL1, 2 modes	2.7		
				IDLE1, 2 modes			
			f _s = 32.768 kHz	SLOW mode	2.0		
SLEEP mode							
	STOP mode						
Input High Voltage	V _{IH1}	Except hysteresis input	V _{DD} ≥ 4.5 V	V _{DD} × 0.70	V _{DD}	V	
	V _{IH2}	Hysteresis input		V _{DD} × 0.75			
	V _{IH3}			V _{DD} < 4.5 V			V _{DD} × 0.90
Input Low Voltage	V _{IL1}	Except hysteresis input	V _{DD} ≥ 4.5 V	0	V _{DD} × 0.30	V	
	V _{IL2}	Hysteresis input			V _{DD} × 0.25		
	V _{IL3}				V _{DD} < 4.5 V		V _{DD} × 0.10
Clock Frequency	f _c	XIN, XOUT	V _{DD} = 4.5 to 6 V	0.4	8.0	MHz	
			V _{DD} = 2.7 to 6 V		4.2		
	f _s	XTIN, XTOUT		30.0	34.0	kHz	

Note: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

D.C. Characteristics

(V_{SS} = 0 V, T_{opr} = -30 to 70°C)

Parameter	Symbol	Pins	Conditions	Min	Typ.	Max	Unit
Hysteresis Voltage	V _{HS}	Hysteresis input		-	0.9	-	V
Input Current	I _{IN1}	TEST	V _{DD} = 5.5 V V _{IN} = 5.5 V/0 V	-	-	± 2	μA
	I _{IN2}	Open drain ports, Tri-state ports					
	I _{IN3}	RESET, STOP					
Input Resistance	R _{IN1}	Port P4 with pull-down		30	70	150	kΩ
	R _{IN2}	RESET		100	220	450	
Pull-down Resistance	R _K	Source open drain ports	V _{DD} = 5.5 V, V _{KK} = -30 V	-	80	-	
Output Leakage Current	I _{LO1}	Sink open drain ports	V _{DD} = 5.5 V, V _{OUT} = 5.5 V	-	-	2	μA
	I _{LO2}	Source open drain ports	V _{DD} = 5.5 V, V _{OUT} = -32 V	-	-	-2	
Output High Voltage	V _{OH2}	Tri-state ports	V _{DD} = 4.5 V, I _{OH} = -0.7 mA	4.1	-	-	V
	V _{OH3}	P8, P9	V _{DD} = 4.5 V, I _{OH} = -5 mA	2.4	-	-	
Output Low Voltage	V _{OL}	Except XOUT	V _{DD} = 4.5 V, I _{OL} = 1.6 mA	-	-	0.4	V
Output High current	I _{OH}	P6, P7	V _{DD} = 4.5 V, V _{OH} = 2.4 V	-	-15	-	mA
Supply Current in NORMAL 1, 2 modes	I _{DD}		V _{DD} = 5.5 V f _c = 8 MHz f _s = 32.768 kHz V _{IN} = 5.3 V/0.2 V	-	10	16	mA
Supply Current in IDLE 1, 2 modes				-	4.5	6	
Supply Current in SLOW mode			V _{DD} = 3.0 V f _s = 32.768 kHz V _{IN} = 2.8 V/0.2 V	-	30	60	μA
Supply Current in SLEEP mode				-	15	30	
Supply Current in STOP mode			V _{DD} = 5.5 V V _{IN} = 5.3 V/0.2 V	-	0.5	10	μA

Note 1: Typical values show those at T_{opr} = 25°C, V_{DD} = 5 V.

Note 2: Input Current I_{IN1}, I_{IN3}; The current through resistor is not included, when the input resistor (pull-up/pull-down) is contained.

Note 3: Typical current consumption during A/D conversion is 1.2 mA.

A/D Conversion Characteristics

(V_{SS} = 0 V, V_{DD} = 4.5 to 5.5 V, T_{opr} = -30 to 70°C)

Parameter	Symbol	Pins	Conditions	Min	Typ.	Max	Unit
Analog Input Voltage Range	V _{CIN}	CIN5 to CIN0		V _{SS}	-	V _{DD}	V
Conversion Error			V _{DD} = 5.0 V	-	-	± 1.5	LSB

A.C. Characteristics

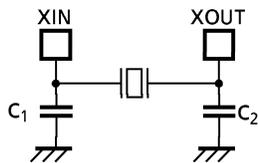
(V_{SS} = 0 V, V_{DD} = 4.5 to 5.5 V, Topr = -30 to 70°C)

Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
Machine Cycle Time	t _{cy}	In NORMAL 1, 2 modes	0.5	—	10	μs
		In IDLE 1, 2 modes				
		In SLOW mode	117.6	—	133.3	
		In SLEEP mode				
High Level Clock Pulse Width	t _{WCH}	For external clock operation (XIN input), f _c = 8 MHz	50	—	—	ns
Low Level Clock Pulse Width	t _{WCL}					
High Level Clock Pulse Width	t _{WSH}	For external clock operation (XTIN input), f _s = 32.768 kHz	14.7	—	—	μs
Low Level Clock Pulse Width	t _{WSL}					

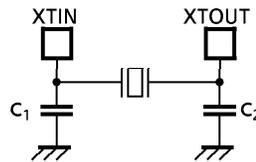
Recommended Oscillating Conditions

(V_{SS} = 0 V, V_{DD} = 4.5 to 5.5 V, Topr = -30 to 70°C)

Parameter	Oscillator	Oscillation Frequency	Recommended Oscillator		Recommended Constant	
					C ₁	C ₂
High-frequency Oscillation	Ceramic Resonator	8 MHz	KYOCERA	KBR8.0M	30 pF	30 pF
		4 MHz	KYOCERA	KBR4.0MS		
	Ceramic Resonator		4 MHz	MURATA	CSA 4.00MG	
		Crystal Oscillator		8 MHz	TOYOCOM	210B 8.0000
Crystal Oscillator	4 MHz		TOYOCOM	204B 4.0000		
Low-frequency Oscillation	Crystal Oscillator	32.768 kHz	NDK	MX-38T	15 pF	15 pF



(1) High-frequency Oscillation



(2) Low-frequency Oscillation

Note: An electrical shield by metal shield plate on the surface of the IC package should be recommendable in order to prevent the device from the high electric fieldstress applied from CRT (Cathode Ray Tube) for continuous reliable operation.